

2SC4617XT1G

General Purpose Transistors NPN Silicon

Description

We declare that the material of product compliance with RoHS requirements

Mechanical Data

- Case: SOT-523 Molded plastic
- Epoxy: UL94V-O rate flame retardant

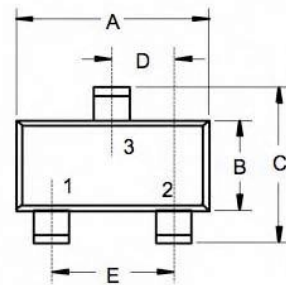
Packing & Order Information

3,000/Reel

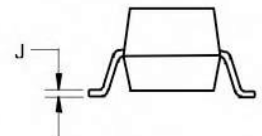
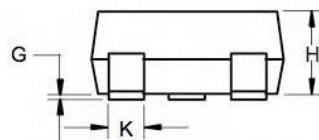


**RoHS
COMPLIANT**

SOT-523

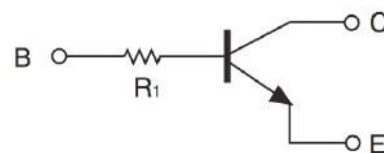


1. Base
2. Emitter
3. Collector



| DIM | DIMENSIONS | | | | NOTE |
|-----|--------------|------|--------------|------|------|
| | INCHES | | MM | | |
| | MIN | MAX | MIN | MAX | |
| A | .059 | .067 | 1.50 | 1.70 | |
| B | .030 | .033 | 0.75 | 0.85 | |
| C | .057 | .069 | 1.45 | 1.75 | |
| D | .020 Nominal | | 0.50 Nominal | | |
| E | .035 | .043 | 0.90 | 1.10 | |
| G | .000 | .004 | .000 | .100 | |
| H | .028 | .031 | .70 | 0.80 | |
| J | .004 | .008 | .100 | .200 | |
| K | .010 | .014 | .25 | .35 | |

Graphic symbol



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Absolute maximum ratings (Ta=25°C)

| Symbol | Parameter | Value | Unit |
|------------------|---------------------------|-------------|------|
| V _{CB0} | Collector-Base Voltage | 60 | V |
| V _{CE0} | Collector-Emitter Voltage | 50 | V |
| V _{EB0} | Emitter-Base Voltage | 7 | V |
| I _C | Collector Current | 0.15 | A |
| P _C | Collector Dissipation | 0.15 | W |
| T _j | Junction Temperature | 150 | °C |
| T _{stg} | Storage Temperature Range | -55 to +150 | °C |

2SC4617XT1G

General Purpose Transistors NPN Silicon

ELECTRICAL CHARACTERISTICS @ Ta=25°C unless otherwise specified

| Symbol | Parameter | Test Conditions | MIN | TYP | MAX | UNIT |
|----------------------|--------------------------------------|---|-----|-----|-----|------|
| BV _{CBO} | Collector-base breakdown voltage | I _C = 50μA | 60 | | | V |
| BV _{CEO} | Collector-emitter breakdown voltage | I _C = 1 mA | 50 | | | V |
| BV _{EBO} | Emitter-base breakdown voltage | I _E = 50μA | 7 | | | V |
| I _{CBO} | Collector cut-off current | V _{CB} = 60 V | | | 0.1 | μA |
| I _{EBO} | Emitter cut-off current | V _{EB} = 7 V | | | 0.1 | μA |
| h _{FE} | DC current gain | V _{CE} = 6 V , I _C = 1 mA | 120 | | 560 | -- |
| V _{CE(sat)} | Collector-emitter saturation voltage | I _C /I _B = 50 mA / 5 mA | | | 0.5 | V |
| f _T | Transition frequency | V _{CE} = 12 V , I _E = 2 mA f = 30MHz | | 180 | | MHz |
| C _{ob} | Collector output capacitance | V _{CB} = 12 V , I _E = 0 A f = 1.0MHz | | 2.0 | 3.5 | pF |

h_{FE} values are classified as follows :

| Item | Q | R | S |
|-----------------|---------|---------|---------|
| h _{FE} | 120-170 | 180-390 | 270-560 |

ORDERING INFORMATION

| Device | Marking | Shipping |
|-------------|---------|-------------------|
| 2SC4617QT1G | BQ | 3000 Tape & Reel |
| 2SC4617QT3G | BQ | 10000 Tape & Reel |
| 2SC4617RT1G | BR | 3000 Tape & Reel |
| 2SC4617RT3G | BR | 10000 Tape & Reel |
| 2SC4617ST1G | BS | 3000 Tape & Reel |
| 2SC4617ST3G | BS | 10000 Tape & Reel |

2SC4617XT1G

General Purpose Transistors NPN Silicon

■ RATINGS AND CHARACTERISTIC CURVES

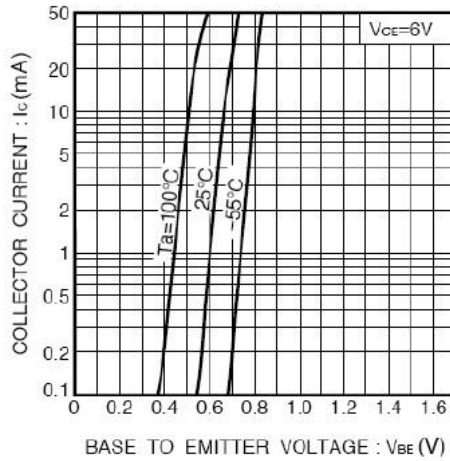


FIG.1 - GROUNDED EMITTER PROPAGATION CHARACTERISTICS

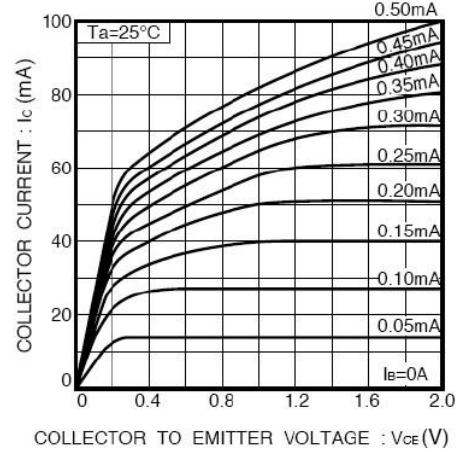


FIG.2 - GROUNDED EMITTER PROPAGATION CHARACTERISTICS (I)

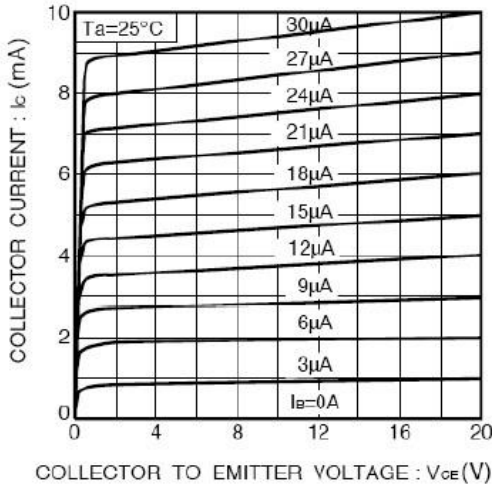


FIG.3 - GROUNDED EMITTER PROPAGATION CHARACTERISTICS (II)

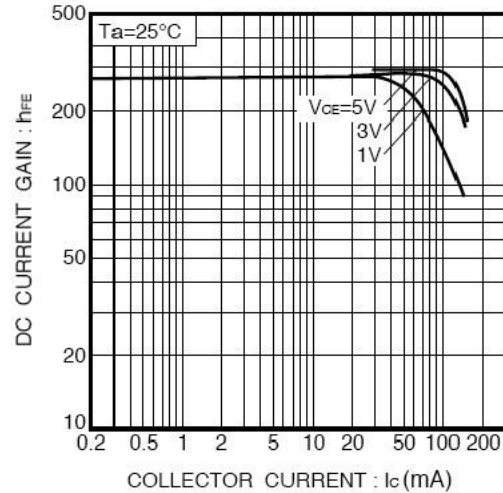


FIG.4 - DC CURRENT GAIN VS. COLLECTOR CURRENT (I)

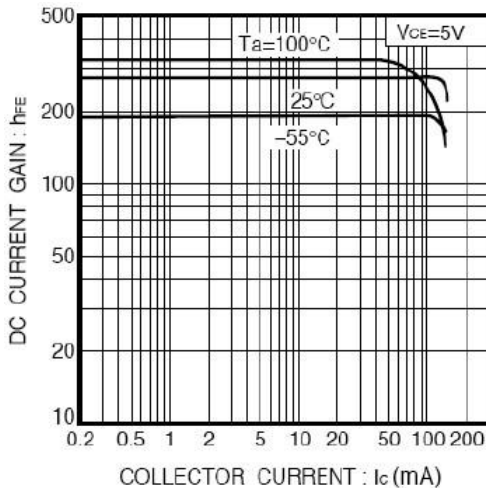


FIG.5 - DC CURRENT GAIN VS. COLLECTOR CURRENT (II)

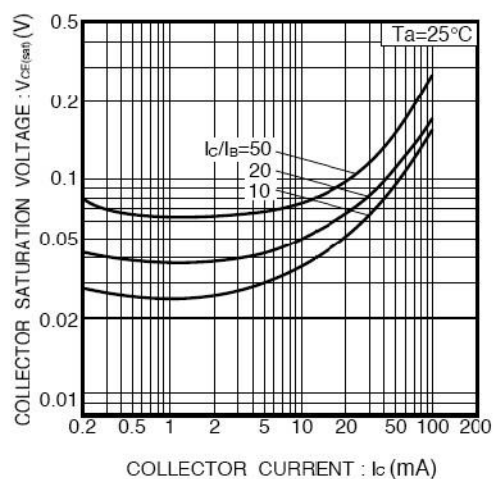


FIG.6 - COLLECTOR-EMITTER SATURATION VOLTAGE VS. COLLECTOR CURRENT

2SC4617XT1G

General Purpose Transistors NPN Silicon

■ RATINGS AND CHARACTERISTIC CURVES

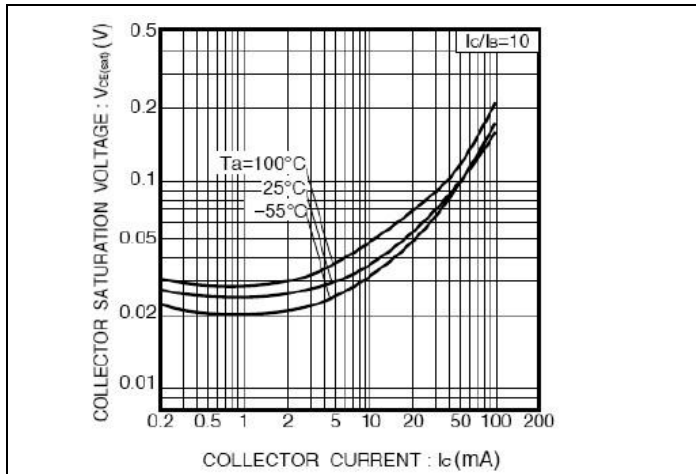


FIG.7 –COLLECTOR-EMITTER SATURATION VOLTAGE VS. COLLECTOR CURRENT(II)

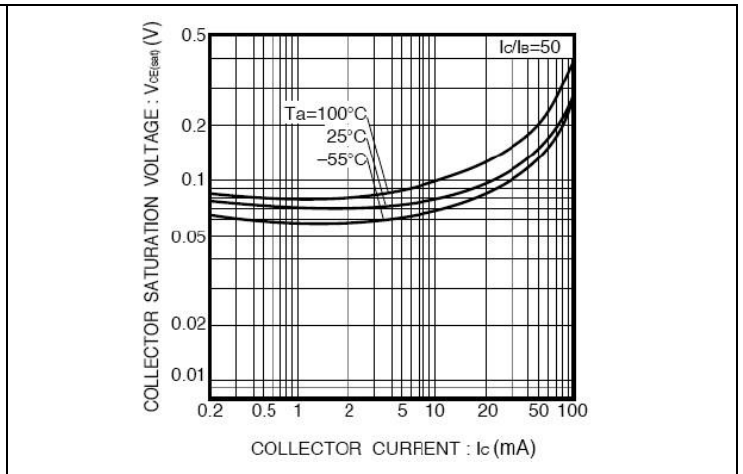


FIG.8 –COLLECTOR-EMITTER SATURATION VOLTAGE VS. COLLECTOR CURRENT(III)

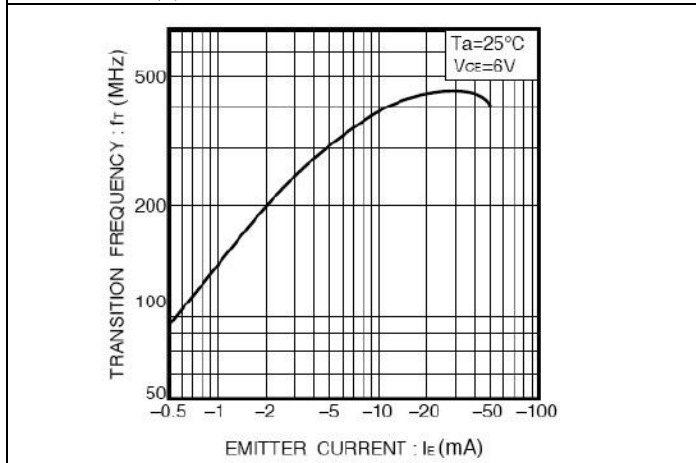


FIG.9 –GAIN BANDWIDTH PRODUCT VS. EMITTER CURRENT

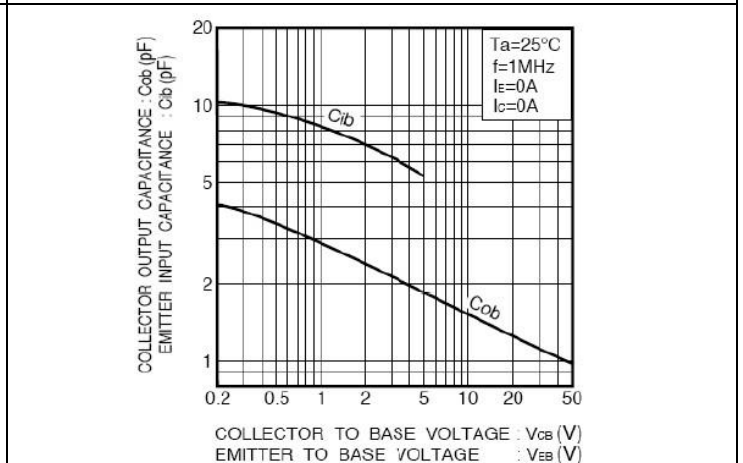


FIG.10 –COLLECTOR OUTPUT CAPACITANCE VS.COLLECTOR-BASE VOLTAGE

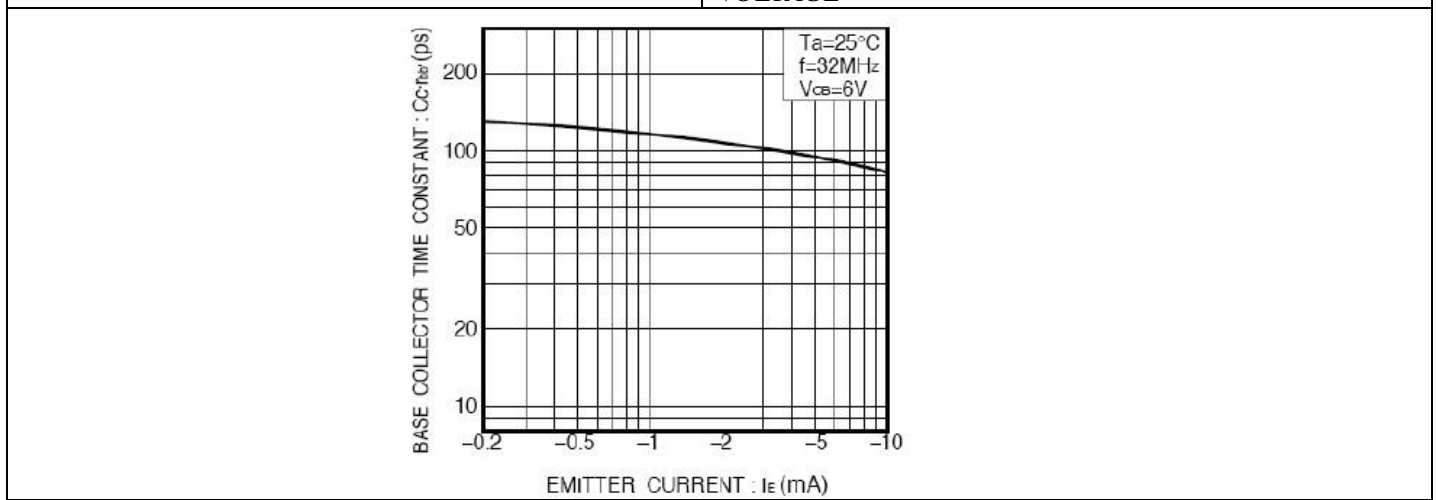


FIG.11 –BASE-COLLECTOR TIME CONSTANCT VS. EMITTER CURRENT

2SC4617XT1G

General Purpose Transistors NPN Silicon

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE

WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Bruckewell Technology Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Bruckewell"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Bruckewell makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Bruckewell disclaims

- (i) Any and all liability arising out of the application or use of any product.
- (ii) Any and all liability, including without limitation special, consequential or incidental damages.
- (iii) Any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Bruckewell's knowledge of typical requirements that are often placed on Bruckewell products in generic applications.

Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time.

Product specifications do not expand or otherwise modify Bruckewell's terms and conditions of purchase, including but not limited to the warranty expressed therein.